International Application No.: PCT/JP2004/005077

U.S. Patent Application No.: Unknown

December 19, 2005

Page 5 of 7

## **AMENDMENTS TO THE CLAIMS:**

This listing of claims will replace all prior versions, and listings, of claims in the application:

## **LISTING OF CLAIMS:**

Claims 1-9 (canceled).

Claim 10 (new): A surface acoustic wave sensor for detecting the minute mass applied to a surface acoustic wave element on the basis of the change in frequency using an SH-type surface acoustic wave, the surface acoustic wave sensor comprising:

a rotated Y-cut LiTaO<sub>3</sub> substrate having Euler angles of (0°, 0° to 18°, 0°  $\pm$  5°) or (0°, 58° to 180°, 0°  $\pm$  5°);

electrodes, principally containing Au, and arranged on the LiTaO<sub>3</sub> substrate to excite a surface acoustic wave; and

a reaction membrane, bound to a target substance or a binding substance bound to the target substance, covering the electrodes arranged on the LiTaO<sub>3</sub> substrate; wherein

the electrodes have a normalized thickness of about 0.8% to about 9.5%, the normalized thickness being determined by normalizing the thickness of the electrodes by the wavelength of the surface acoustic wave.

Claim 11 (new): The surface acoustic wave sensor according to Claim 10, wherein the rotated Y-cut LiTaO<sub>3</sub> substrate has Euler angles of  $(0^{\circ}, 120^{\circ} \text{ to } 140^{\circ}, 0^{\circ} \pm 5^{\circ})$ .

Claim 12 (new): The surface acoustic wave sensor according to Claim 10, further comprising a bonding layer, placed between the reaction membrane and the electrodes, and arranged to improve the bond between the reaction membrane and the electrodes.

International Application No.: PCT/JP2004/005077

U.S. Patent Application No.: Unknown

December 19, 2005

Page 6 of 7

Claim 13 (new): The surface acoustic wave sensor according to Claim 10, further comprising a protective layer, placed between the reaction membrane and the

electrodes, lying over the electrodes and regions outside the electrodes.

Claim 14 (new): The surface acoustic wave sensor according to Claim 12, further

comprising a protective layer, placed between the bonding layer and the electrodes,

lying over the electrodes and regions outside the electrodes.

Claim 15 (new): The surface acoustic wave sensor according to Claim 10,

wherein the electrodes have a normalized thickness of about 1.2% to about 8.5%, the

normalized thickness being determined by normalizing the thickness of the electrodes

by the wavelength of the surface acoustic wave.

Claim 16 (new): The surface acoustic wave sensor according to Claim 15,

wherein the electrodes have a normalized thickness of about 1.9% to about 6.6%, the

normalized thickness being determined by normalizing the thickness of the electrodes

by the wavelength of the surface acoustic wave.

Claim 17 (new): The surface acoustic wave sensor according to Claim 16,

wherein the electrodes have a normalized thickness of about 3.0% to about 5.0%, the

normalized thickness being determined by normalizing the thickness of the electrodes

by the wavelength of the surface acoustic wave.

Claim 18 (new): A biosensor comprising the surface acoustic wave sensor

according to Claim 10, wherein the reaction membrane includes a substance bound to a

biological substance that is a target substance and the mass applied to a surface of the

substrate of the surface acoustic wave sensor is varied due to the bind of the biological

substance to the reaction membrane.